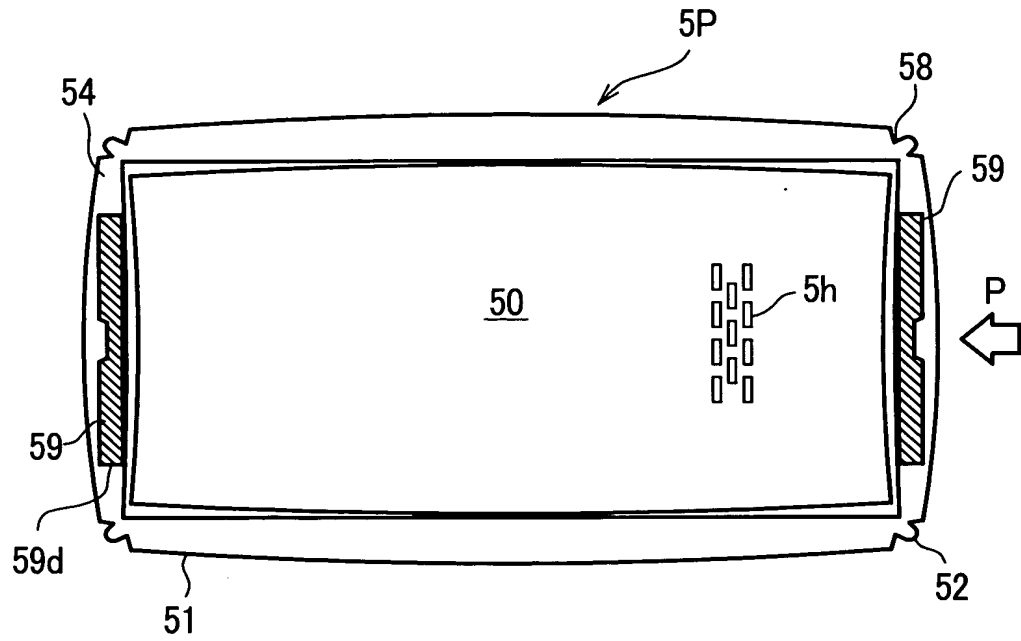
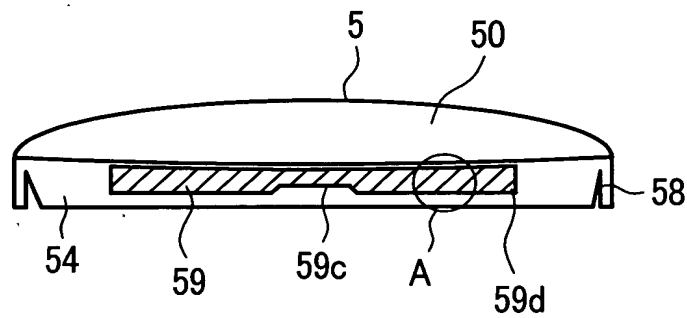


*FIG. 1*



*FIG. 2*



*FIG. 3*

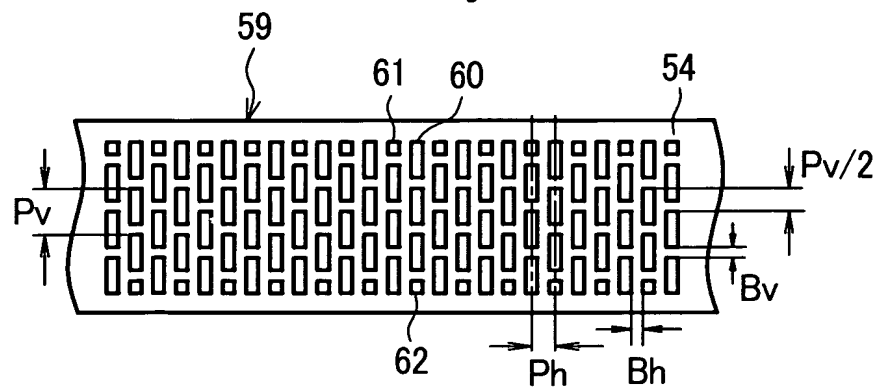
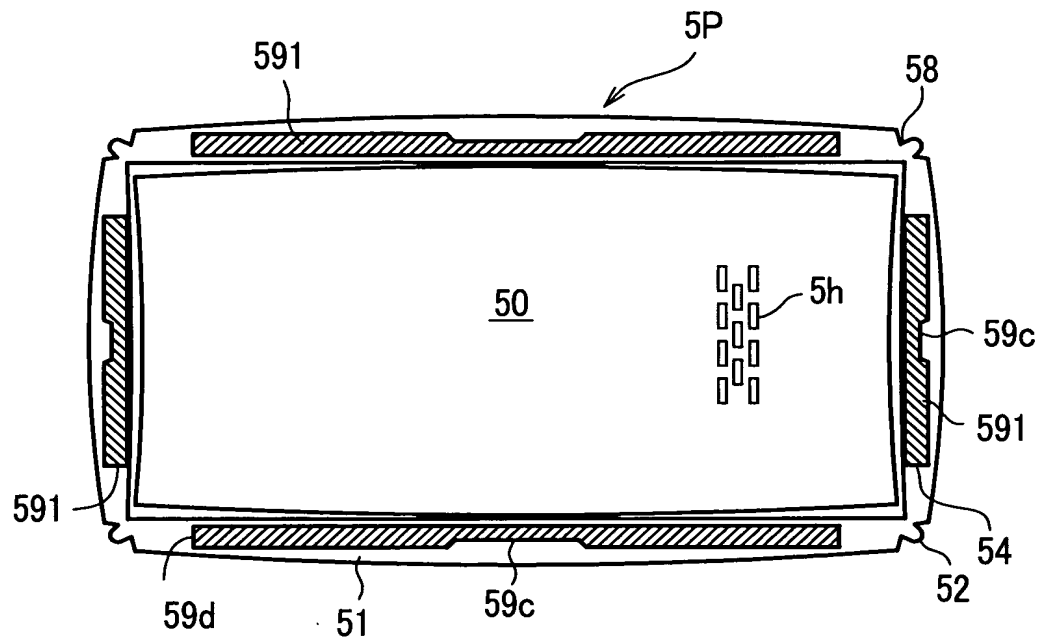


Figure 1B is a side view of the first electrode 59. The electrode has a central rectangular portion 59a with width L2 and a larger base portion 59b with width L1. The base portion 59b has a height W1, and the central portion 59a has a height W2. The electrode is shown in cross-section with a top surface 59e and a bottom surface 59d. A circular feature B is located on the left side of the electrode.

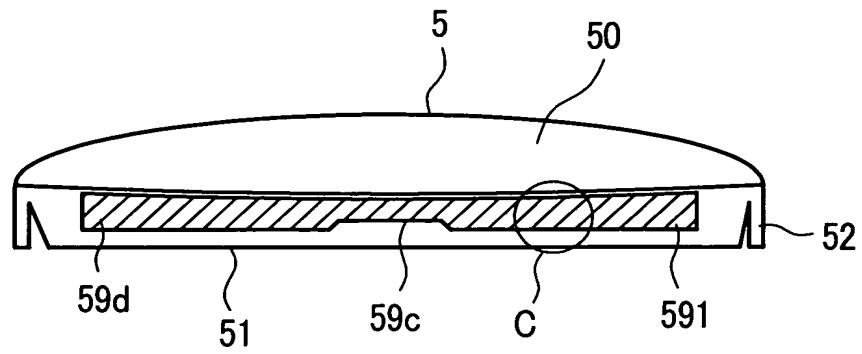
Diagram illustrating a plan view of a semiconductor device structure, showing a grid of rectangular regions (62) defined by various dimensions and features:

- Dimensions:**
  - $BH1$ ,  $BH2$ ,  $BH3$ : Vertical dimensions of rectangular regions.
  - $SL1$ ,  $SL2$ ,  $SL3$ ,  $SL4$ : Vertical dimensions of rectangular regions.
  - $SW1$ ,  $SW2$ ,  $SW3$ : Horizontal dimensions of rectangular regions.
  - $BV1$ ,  $BV2$ ,  $BV3$ : Horizontal dimensions of rectangular regions.
  - $PV$ ,  $PV/2$ : Vertical dimensions of rectangular regions.
  - $PH$ : Horizontal dimension of a rectangular region.
- Features:**
  - $59$ : A curved boundary or feature on the left side.
  - $59e$ : A specific feature on the curved boundary.
  - $61$ : A wavy horizontal line across the middle of the grid.
  - $62$ : The rectangular regions themselves.

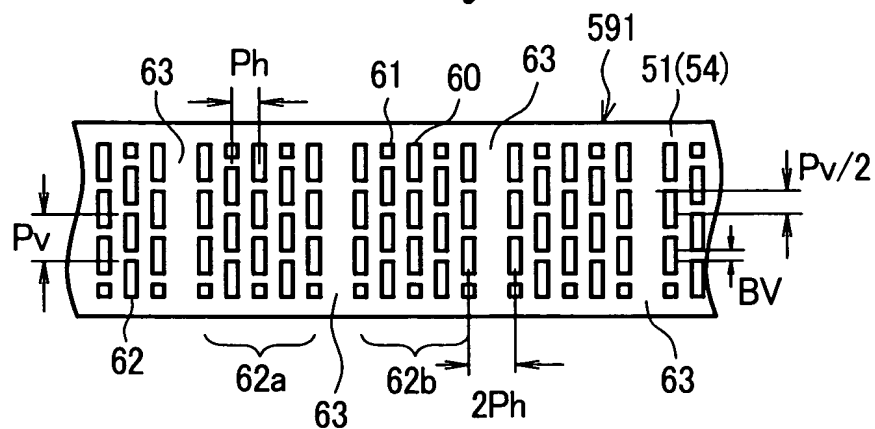
**FIG. 6**



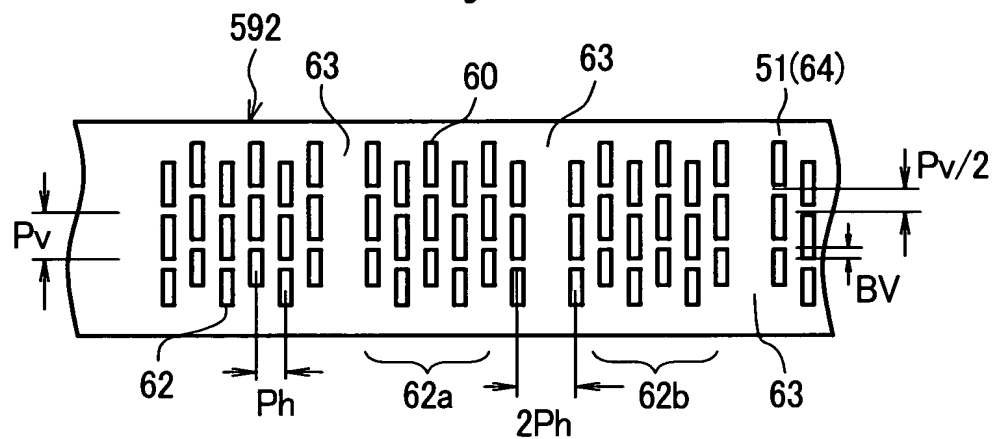
**FIG. 7**



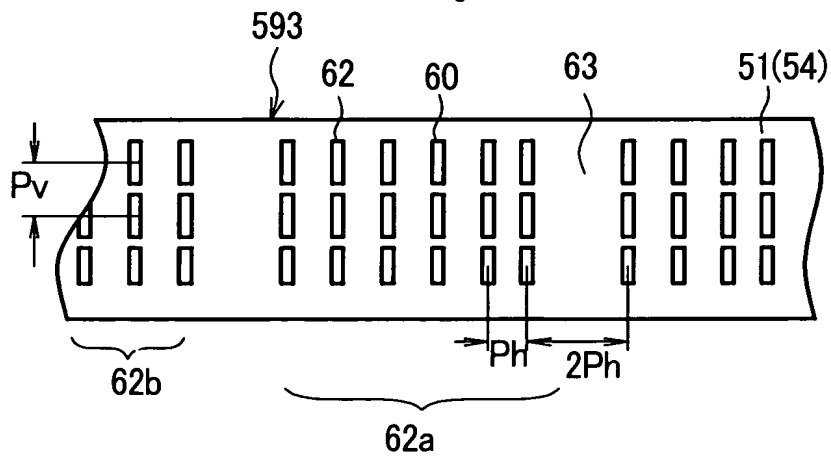
**FIG. 8**



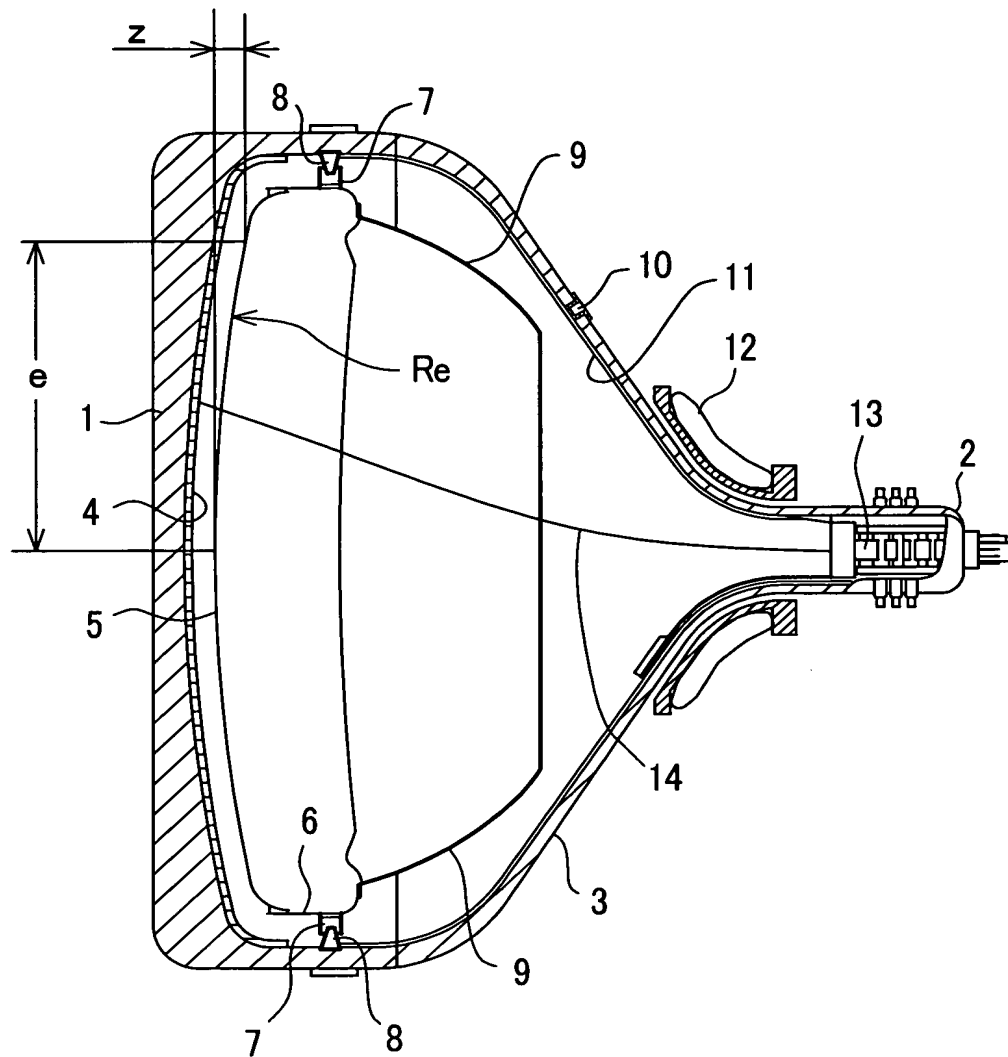
**FIG. 9**



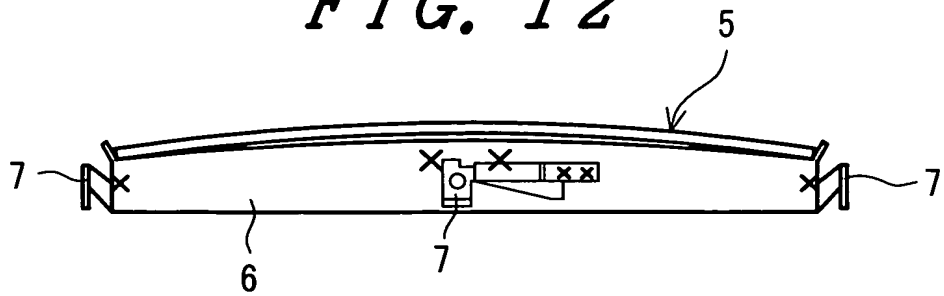
**FIG. 10**



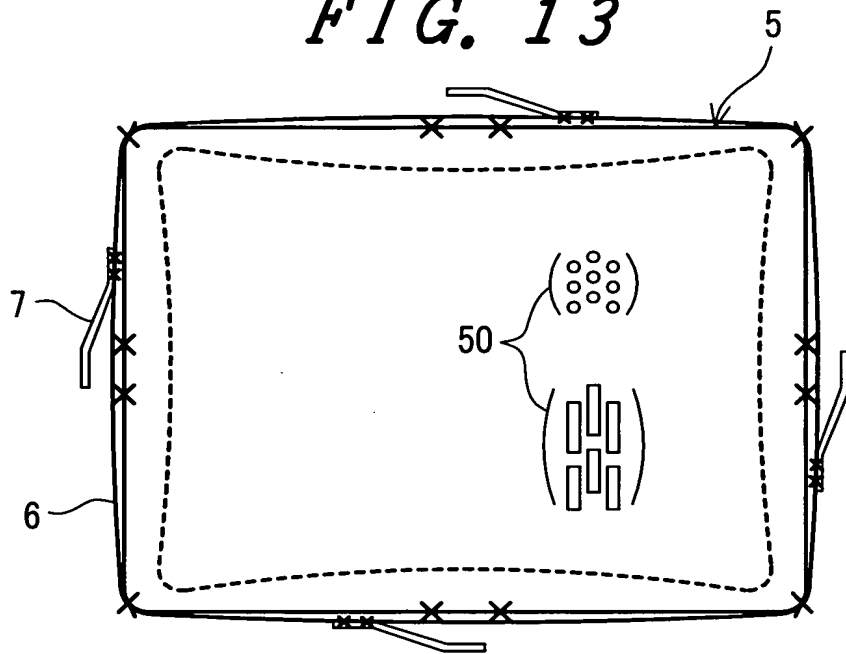
*FIG. 11*



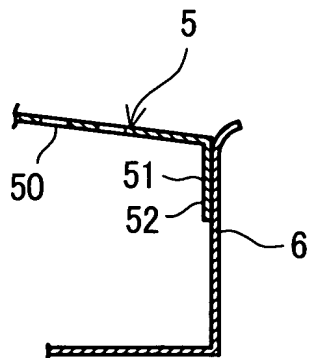
*FIG. 12*



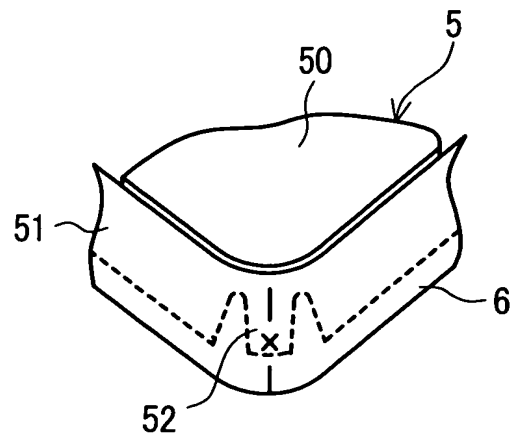
*FIG. 13*



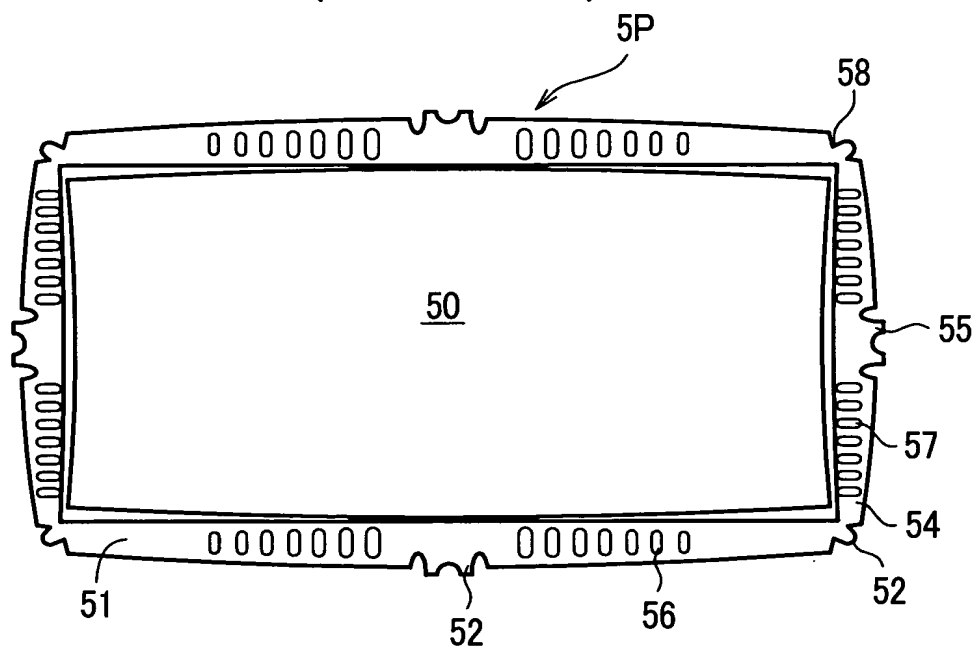
*FIG. 14*



*FIG. 15*



**FIG. 16**  
(PRIOR ART)



**FIG. 17**  
(PRIOR ART)

